

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

- Low-Cost Single-Channel High-Speed MOSFET Driver
- I_{CC} . . . 15- μ A Max (TPS2828, TPS2829)
- 25-ns Max Rise/Fall Times and 40-ns Max Propagation Delay . . . 1-nF Load
- 2-A Peak Output Current
- 4-V to 14-V Driver Supply Voltage Range; Internal Regulator Extends Range to 40 V (TPS2816, TPS2817, TPS2818, TPS2819)
- 5-pin SOT-23 Package
- -40°C to 125°C Ambient-Temperature Operating Range
- Highly Resistant to Latch-ups

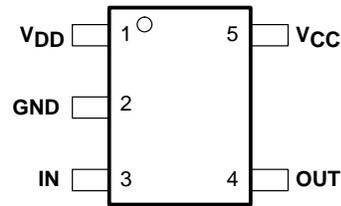
description

The TPS28xx single-channel high-speed MOSFET drivers are capable of delivering peak currents of up to 2 A into highly capacitive loads. High switching speeds (t_r and $t_f = 14$ ns typ) are obtained with the use of BiCMOS outputs. Typical threshold switching voltages are $2/3$ and $1/3$ of V_{CC} . The design inherently minimizes shoot-through current.

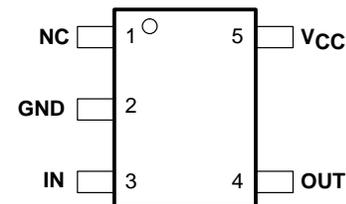
A regulator is provided on TPS2816 through TPS2819 devices to allow operation with supply inputs between 14 V and 40 V. The regulator output can be used to power other circuits, provided power dissipation does not exceed package limitations. If the regulator is not required, V_{DD} (the regulator input) should be connected to V_{CC} . The TPS2816 and TPS2817 input circuits include an active pullup circuit to eliminate the need for an external resistor when using open-collector PWM controllers. The TPS2818 and TPS2819 are identical to the TPS2816 and TPS2817, except that the active pullup circuit is omitted. The TPS2828 and TPS2829 are identical to the TPS2818 and TPS2819, except that the internal voltage regulator is omitted, allowing quiescent current to drop to less than 15 μ A when the inputs are high or low.

The TPS28xx series devices are available in 5-pin SOT-23 (DBV) packages and operate over an ambient temperature range of -40°C to 125°C .

TPS2816, TPS2817
TPS2818, TPS2819
DBV PACKAGE
(TOP VIEW)



TPS2828, TPS2829
DBV PACKAGE
(TOP VIEW)



NC – No internal connection

AVAILABLE OPTIONS

T _A	FUNCTION	PACKAGED DEVICES	CHIP FORM
		SOT-23-5 (DBV)	(Y)
-40°C to 125°C	Inverting driver with active pullup input	TPS2816DBV	TPS2816Y
	Noninverting driver with active pullup input	TPS2817DBV	TPS2817Y
	Inverting driver	TPS2818DBV	TPS2818Y
	Noninverting driver	TPS2819DBV	TPS2819Y
	Inverting driver, no regulator	TPS2828DBV	TPS2828Y
	Noninverting driver, no regulator	TPS2829DBV	TPS2829Y

The DBV package is available taped and reeled only.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

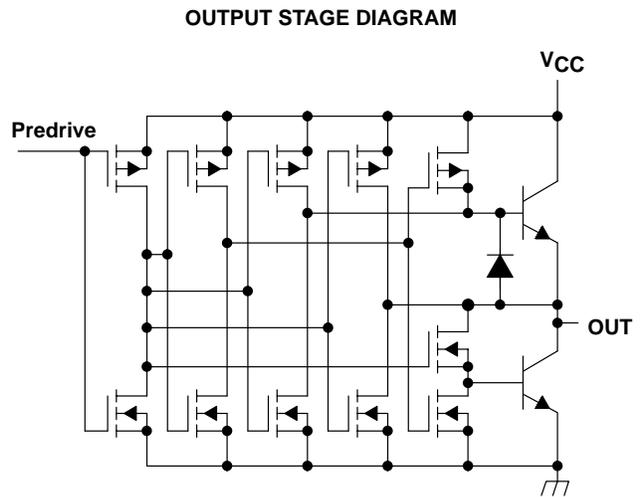
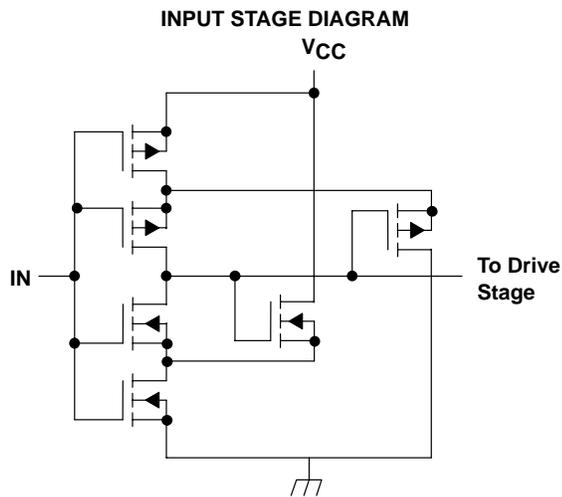
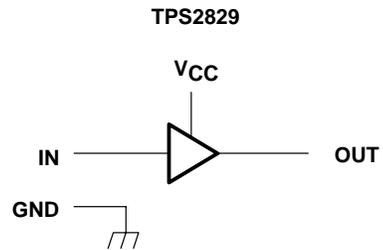
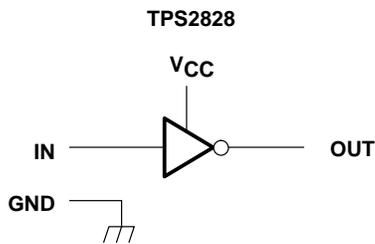
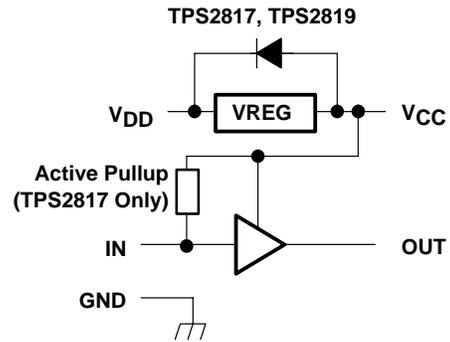
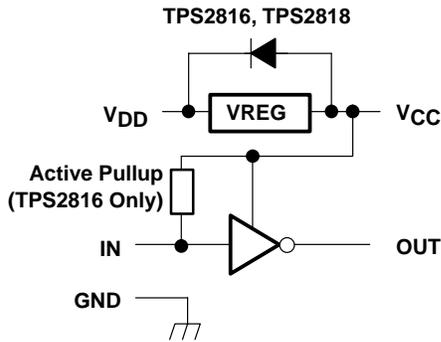
 **TEXAS
INSTRUMENTS**
www.ti.com

Copyright © 2002, Texas Instruments Incorporated

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

functional block diagram

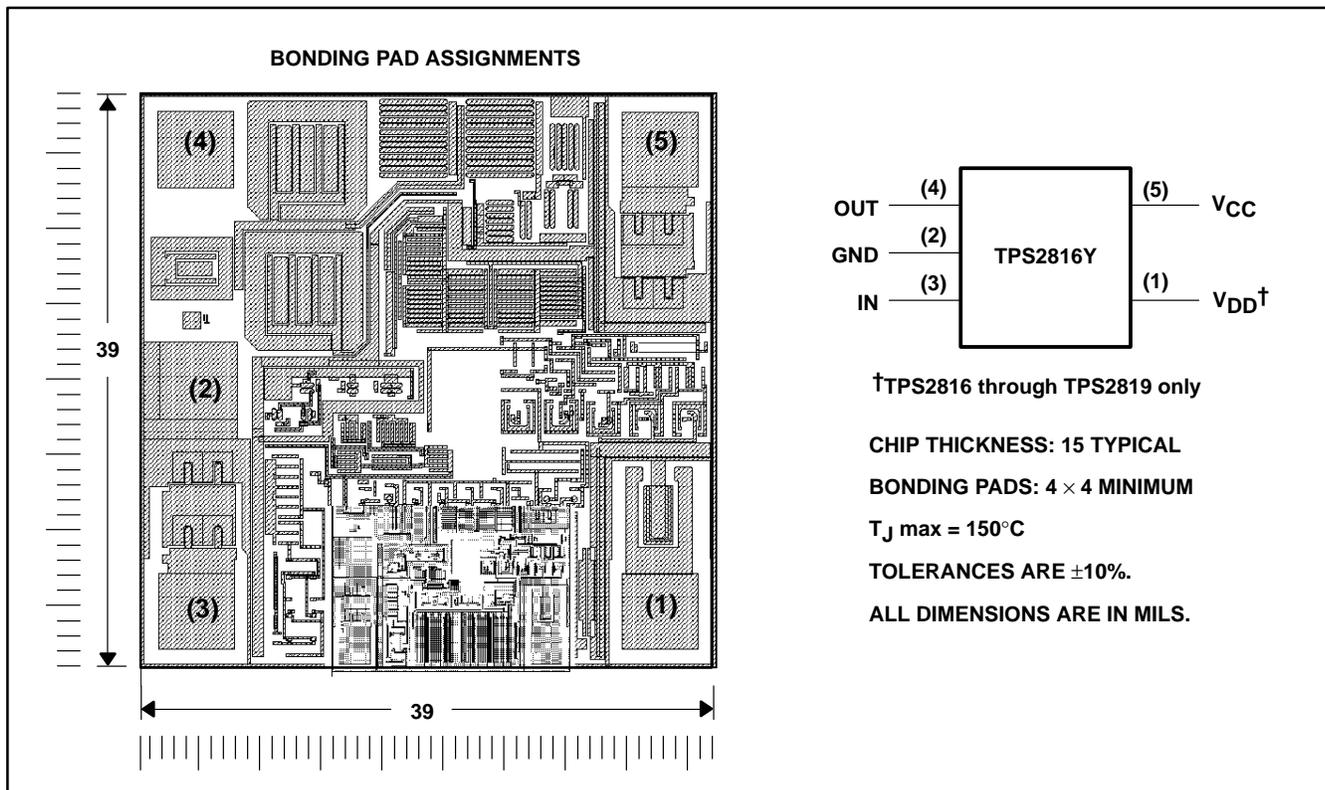


TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

TPS28xxY chip information

This chip, when properly assembled, displays characteristics similar to those of the TPS28xx. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. The chip may be mounted with conductive epoxy or a gold-silicon preform.



Terminal Functions

TPS2816, TPS2818, TPS2828 (inverting driver)

TERMINAL		DESCRIPTION
NAME	NO.	
V _{DD}	1	Regulator supply voltage input. (Not connected on TPS2828)
GND	2	Ground
IN	3	Driver input.
OUT	4	Driver output, OUT = $\overline{\text{IN}}$
V _{CC}	5	Driver supply voltage/regulator output voltage

TPS2817, TPS2819, TPS2829 (noninverting driver)

TERMINAL		DESCRIPTION
NAME	NO.	
V _{DD}	1	Regulator supply voltage input. (Not connected on TPS2829)
GND	2	Ground
IN	3	Driver input.
OUT	4	Driver output, OUT = IN
V _{CC}	5	Driver supply voltage/regulator output voltage

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 80°C POWER RATING
DBV	437 mW	3.5 mW/°C	280 mW	227 mW

These dissipation ratings are based upon EIA specification JESD51-3, "Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages," in tests conducted in a zero-airflow, wind tunnel environment.

absolute maximum ratings over operating temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.3 V to 15 V
Regulator supply voltage range, V _{DD}	V _{CC} –0.3 V to 42 V
Input voltage range, I _N	–0.3 V to V _{CC} +0.5 V
Output voltage range, (pin 4)	–0.5 V to V _{CC} +0.5 V
Continuous regulator output current, V _{CC}	25 mA
Continuous output current, OUT	±100 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating ambient temperature range, T _A	–40°C to 125°C
Storage temperature range, T _{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16inch) from case for 10 seconds	260°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to device GND terminal.

recommended operating conditions

	MIN	MAX	UNIT
Regulator input voltage range, V _{DD} , TPS2816 through TPS2819	8	40	V
Supply voltage, V _{CC}	4	14	V
Input voltage, I _N	–0.3	V _{CC}	V
Continuous regulator output current, I _{CC}	0	20	mA
Operating ambient temperature range, T _A	–40	125	°C

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

TPS28xx electrical characteristics over recommended operating ambient temperature range, $V_{CC} = 10\text{ V}$, V_{DD} tied to V_{CC} , $C_L = 1\text{ nF}$ (unless otherwise specified)

Inputs

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Positive-going input threshold voltage	$V_{CC} = 5\text{ V}$		3.3	4	V
	$V_{CC} = 10\text{ V}$		6.6	7	
	$V_{CC} = 14\text{ V}$		9.3	10	
Negative-going input threshold voltage	$V_{CC} = 5\text{ V}$	1	1.7		V
	$V_{CC} = 10\text{ V}$	2	3.3		
	$V_{CC} = 14\text{ V}$	2.5	4.6		
Input voltage hysteresis			1.3		V
Input current, TPS2818/19/28/29	Input = 0 V or V_{CC}		0.2		μA
Input current, TPS2816/17	Input = 0 V		650		μA
	Input = V_{CC}		15		
Input capacitance			5	10	pF

† Typical values are for $T_A = 25^\circ\text{C}$ unless otherwise noted.

Outputs

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
High-level output voltage	$I_O = -1\text{ mA}$	9.75	9.9		V
	$I_O = -100\text{ mA}$	8	9.1		
Low-level output voltage	$I_O = 1\text{ mA}$		0.18	0.25	V
	$I_O = 100\text{ mA}$		1	2	

† Typical values are for $T_A = 25^\circ\text{C}$ unless otherwise noted.

regulator, TPS2816 through TPS2819

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Output voltage	$14 \leq V_{DD} \leq 40\text{ V}$, $0 \leq I_O \leq 20\text{ mA}$	10	11.5	13	V
Output voltage in dropout	$I_O = 10\text{ mA}$, $V_{DD} = 10\text{ V}$	8		10	V

† Typical values are for $T_A = 25^\circ\text{C}$ unless otherwise noted.

supply current

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Supply current into V_{CC}	TPS2816, TPS2817	$I_N = \text{high} = 10\text{ V}$	150	250	μA
		$I_N = \text{low} = 0\text{ V}$	650	1000	
	TPS2818, TPS2819	$I_N = \text{high or low}$, High = 10 V, Low = 0 V	25	50	
			0.1	15	
Supply current into V_{DD}	TPS2816, TPS2817	$V_{DD} = 20\text{ V}$, $I_N = \text{high} = 10\text{ V}$ or low = 0 V	650	1000	μA
	TPS2818, TPS2819	$V_{DD} = 20\text{ V}$, $I_N = \text{high} = 10\text{ V}$ or low = 0 V	50	150	

† Typical values are for $T_A = 25^\circ\text{C}$ unless otherwise noted.

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

TPS28xxY electrical characteristics at $T_A = 25^\circ\text{C}$, $V_{CC} = 10\text{ V}$, V_{DD} tied to V_{CC} , $C_L = 1\text{ nF}$ (unless otherwise specified)

Inputs

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Positive-going input threshold voltage	$V_{CC} = 5\text{ V}$		3.3		V
	$V_{CC} = 10\text{ V}$		6.6		
	$V_{CC} = 14\text{ V}$		9.3		
Negative-going input threshold voltage	$V_{CC} = 5\text{ V}$		1.7		V
	$V_{CC} = 10\text{ V}$		3.3		
	$V_{CC} = 14\text{ V}$		4.6		
Input voltage hysteresis			1.3		V
Input current, TPS2818/19/28/29	Input = 0 V or V_{CC}		0.2		μA
Input current, TPS2816/17	Input = 0 V		650		μA
	Input = V_{CC}		15		
Input resistance			1000		$\text{M}\Omega$
Input capacitance			5		pF

outputs

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High-level output voltage	$I_O = -1\text{ mA}$		9.9		V
	$I_O = -100\text{ mA}$		9.1		
Low-level output voltage	$I_O = 1\text{ mA}$		0.18		V
	$I_O = 100\text{ mA}$		1		

regulator, TPS2816 through TPS2819

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Output voltage	$14 \leq V_{DD} \leq 40\text{ V}$, $0 \leq I_O \leq 20\text{ mA}$		11.5		V
Output voltage in dropout	$I_O = 10\text{ mA}$, $V_{DD} = 10\text{ V}$		9		V

supply current

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply current into V_{CC}	TPS2816, TPS2817	IN = high = 10 V	150		μA
		IN = low = 0 V	650		
	TPS2818, TPS2819	IN = high or low, High = 10 V, Low = 0 V	25		
			0.1		
Supply current into V_{DD}	TPS2816, TPS2817	$V_{DD} = 20\text{ V}$, IN = high = 10 V or low = 0 V	650		μA
	TPS2818, TPS2819	$V_{DD} = 20\text{ V}$, IN = high = 10 V or low = 0 V	50		

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

switching characteristics for all devices over recommended operating ambient temperature range, $V_{CC} = 10\text{ V}$, V_{DD} tied to V_{CC} , $C_L = 1\text{ nF}$ (unless otherwise specified)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_r	Rise time	$V_{CC} = 14\text{ V}$			25	ns
		$V_{CC} = 10\text{ V}$		14	30	
		$V_{CC} = 5\text{ V}$			35	
t_f	Fall time	$V_{CC} = 14\text{ V}$			25	ns
		$V_{CC} = 10\text{ V}$		14	30	
		$V_{CC} = 5\text{ V}$			35	
t_{PHL}	Propagation delay time, high-to-low-level output	$V_{CC} = 14\text{ V}$			40	ns
		$V_{CC} = 10\text{ V}$		24	45	
		$V_{CC} = 5\text{ V}$			50	
t_{PLH}	Propagation delay time, low-to-high-level output	$V_{CC} = 14\text{ V}$			40	ns
		$V_{CC} = 10\text{ V}$		24	45	
		$V_{CC} = 5\text{ V}$			50	

PARAMETER MEASUREMENT INFORMATION

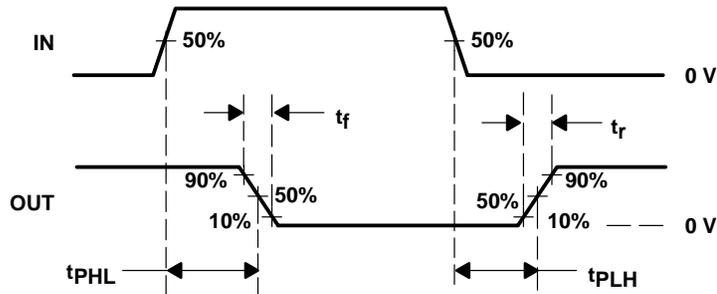


Figure 1. Typical Timing Diagram (TPS2816)

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

PARAMETER MEASUREMENT INFORMATION

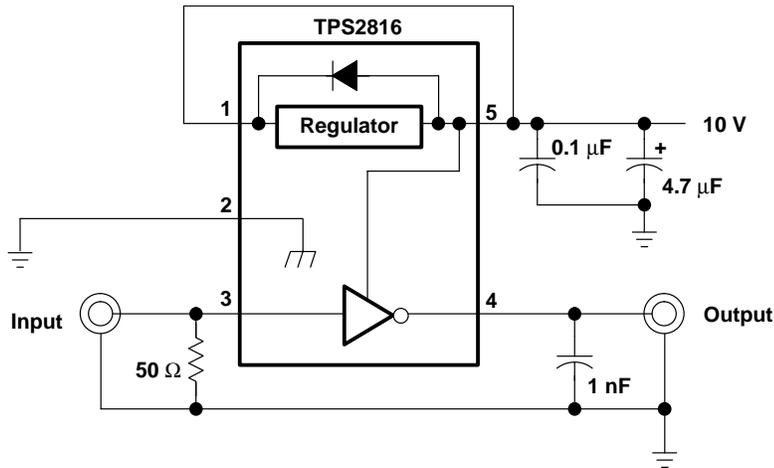


Figure 2. Switching Time Test Setup

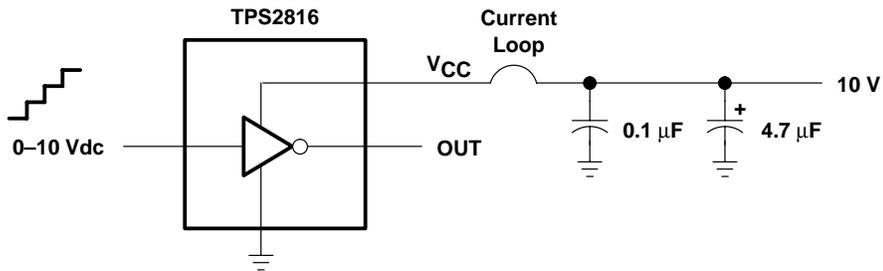


Figure 3. Shoot-Through Current Test Setup

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

TYPICAL CHARACTERISTICS

Table of Graphs

		FIGURE
Rise time	vs Supply voltage	4
Fall time	vs Supply voltage	5
Propagation time (L>H)	vs Supply voltage	6
Propagation Time (H>L)	vs Supply voltage	7
Rise time	vs Ambient temperature	8
Fall time	vs Ambient temperature	9
Propagation time (L>H)	vs Supply voltage	10
Propagation time (H>L)	vs Ambient temperature	11
Supply current (V_{CC})	vs Supply voltage	12
Supply current (V_{CC})	vs Load capacitance	13
Supply current (V_{CC})	vs Ambient temperature	14
Input threshold voltage	vs Supply voltage	15
Regulator output voltage	vs Regulator supply voltage	16
Regulator quiescent current	vs Regulator supply voltage	17
Shoot-through current	vs Input voltage (L>H)	18
Shoot-through current	vs Input voltage (H>L)	19

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

TYPICAL CHARACTERISTICS

RISE TIME
vs
SUPPLY VOLTAGE

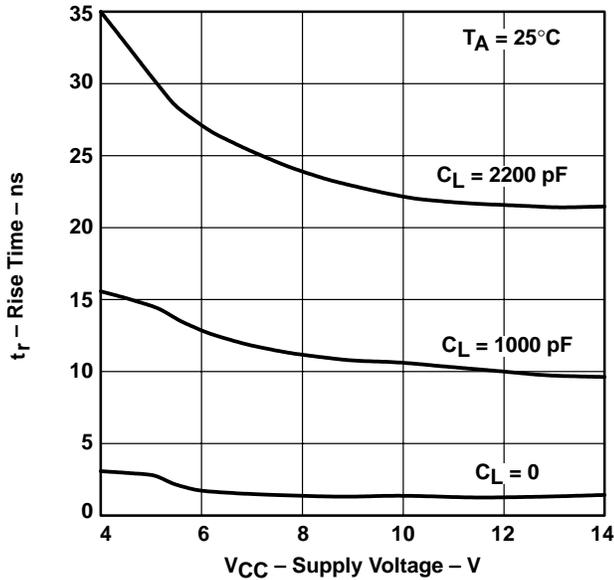


Figure 4

FALL TIME
vs
SUPPLY VOLTAGE

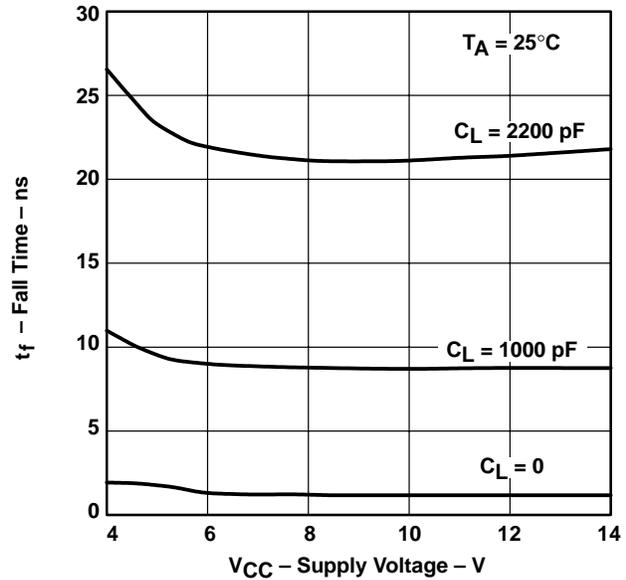


Figure 5

PROPAGATION DELAY TIME,
LOW-TO-HIGH-LEVEL OUTPUT
vs
SUPPLY VOLTAGE

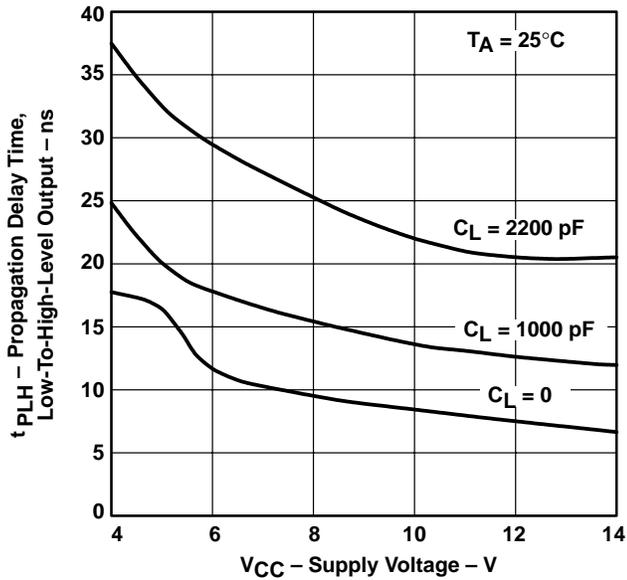


Figure 6

PROPAGATION DELAY TIME,
HIGH-TO-LOW-LEVEL OUTPUT
vs
SUPPLY VOLTAGE

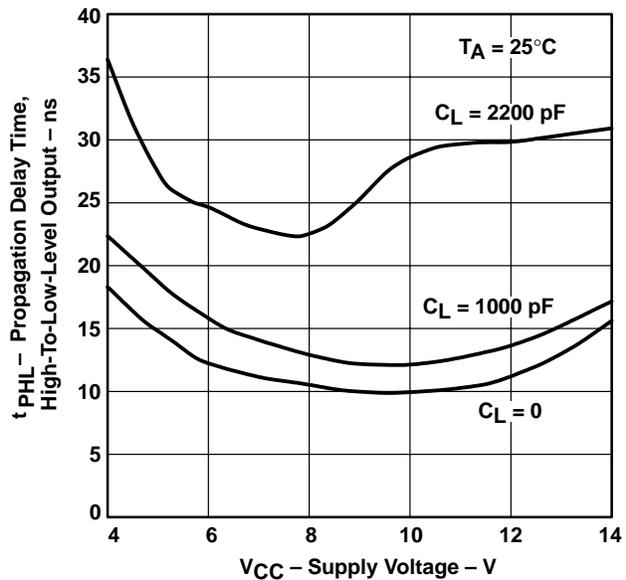


Figure 7

TYPICAL CHARACTERISTICS

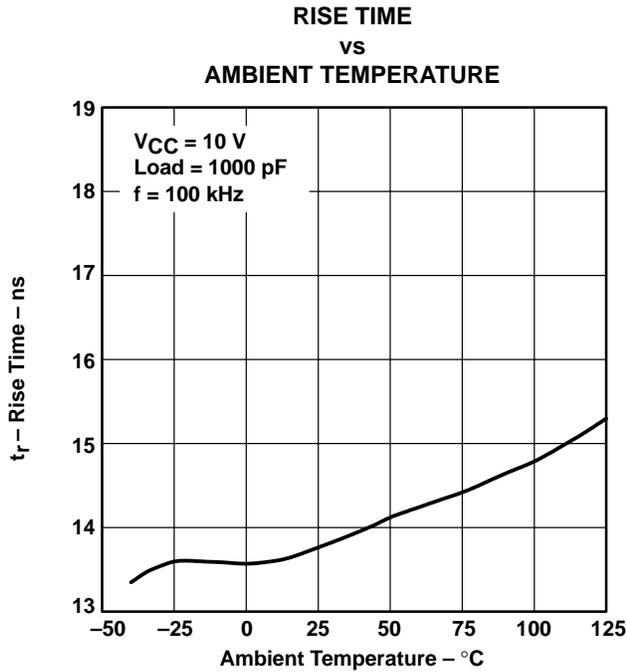


Figure 8

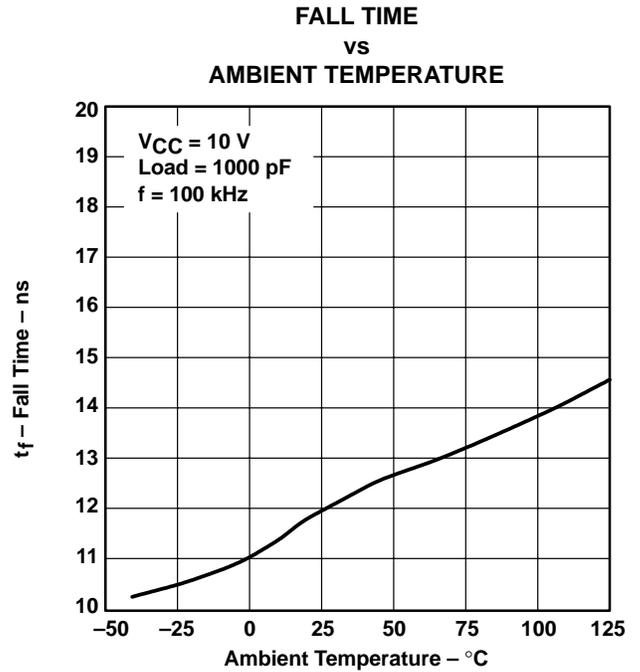


Figure 9

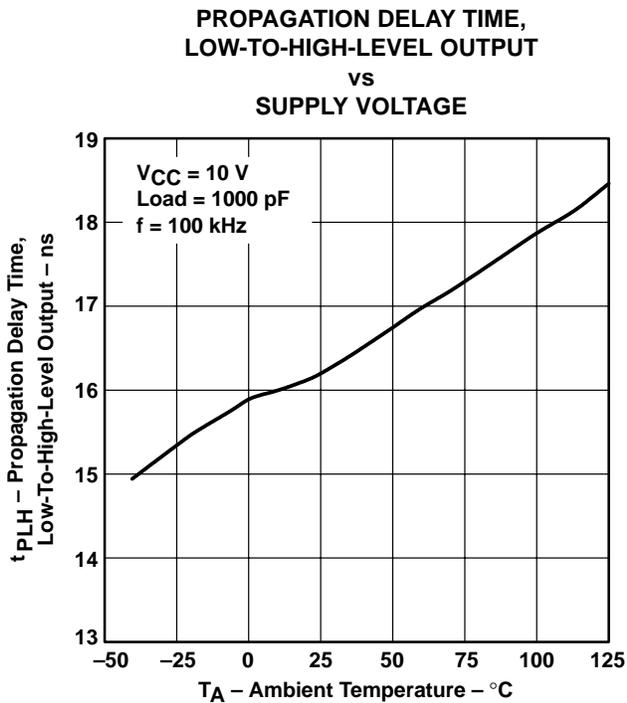


Figure 10

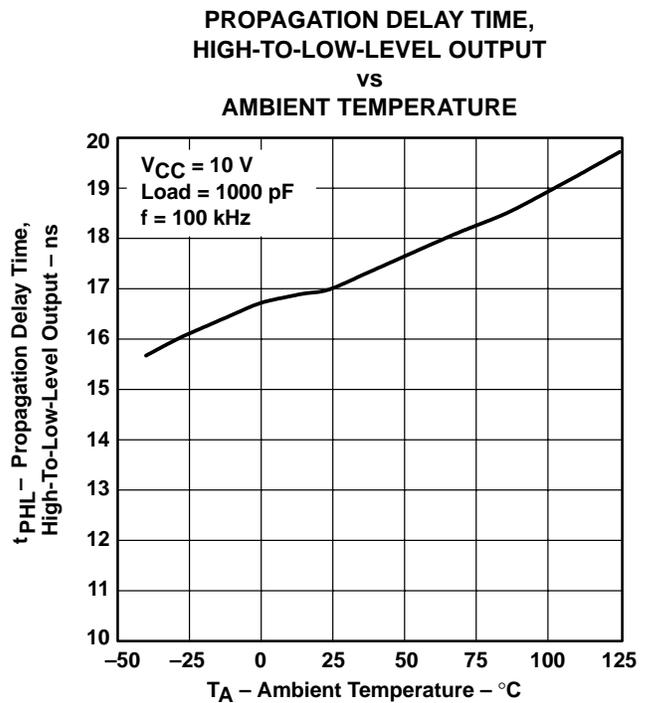


Figure 11

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

TYPICAL CHARACTERISTICS

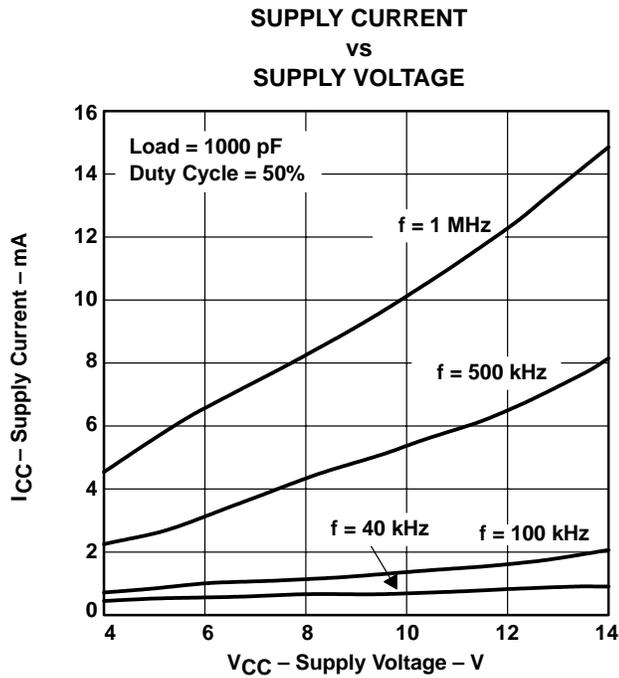


Figure 12

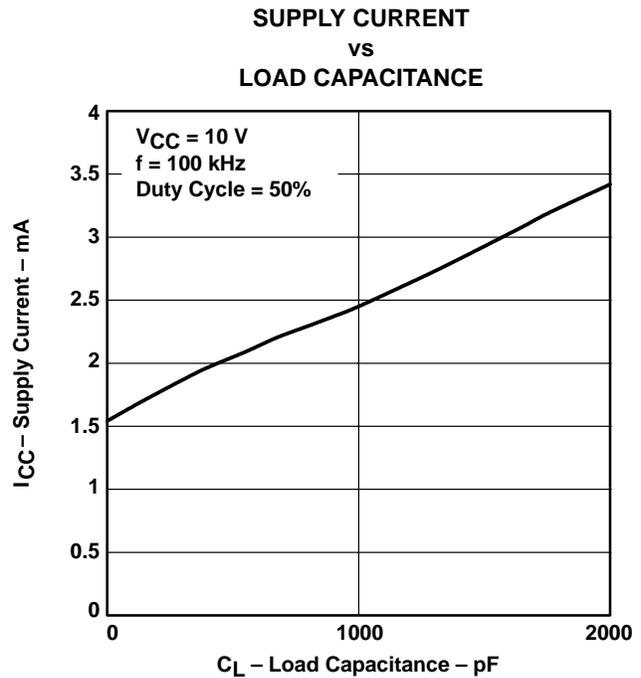


Figure 13

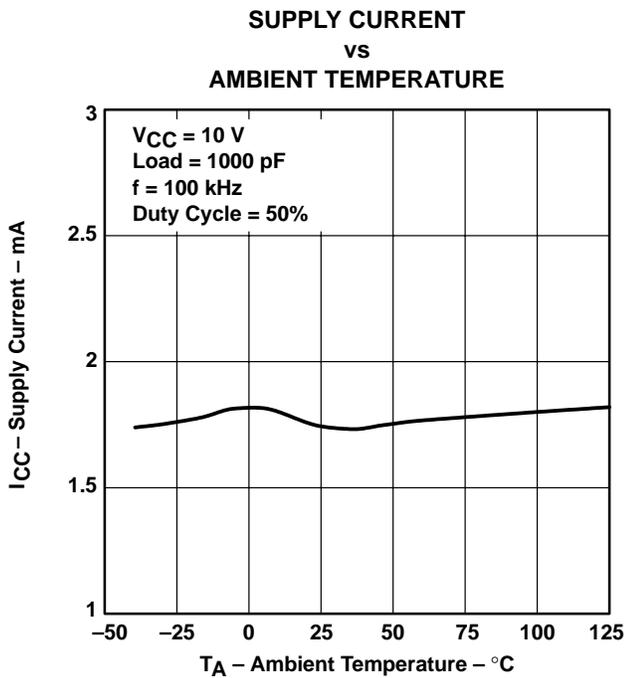


Figure 14

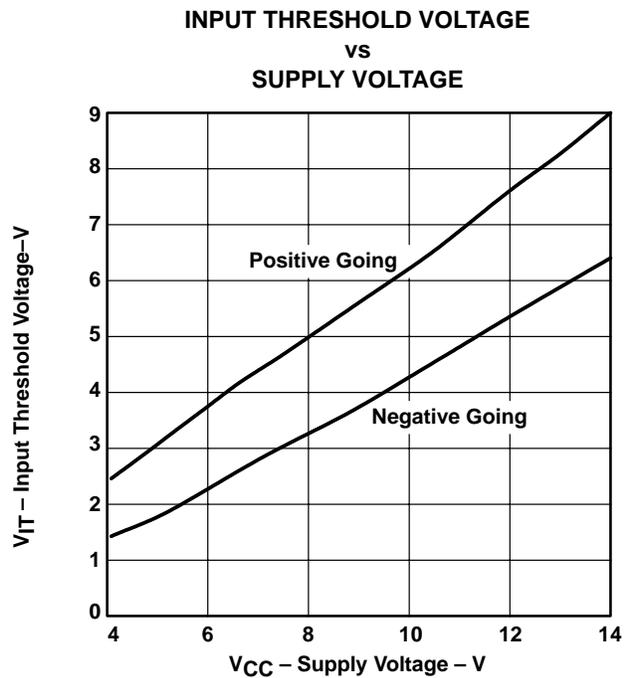


Figure 15

TYPICAL CHARACTERISTICS

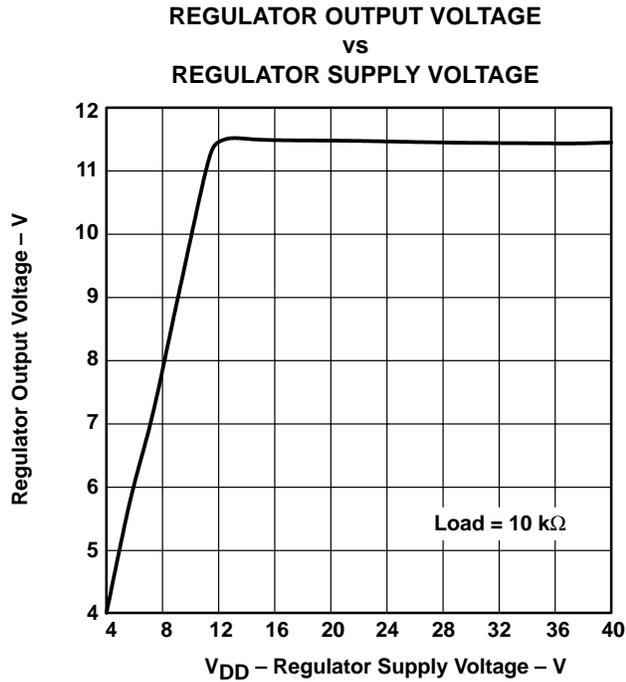


Figure 16

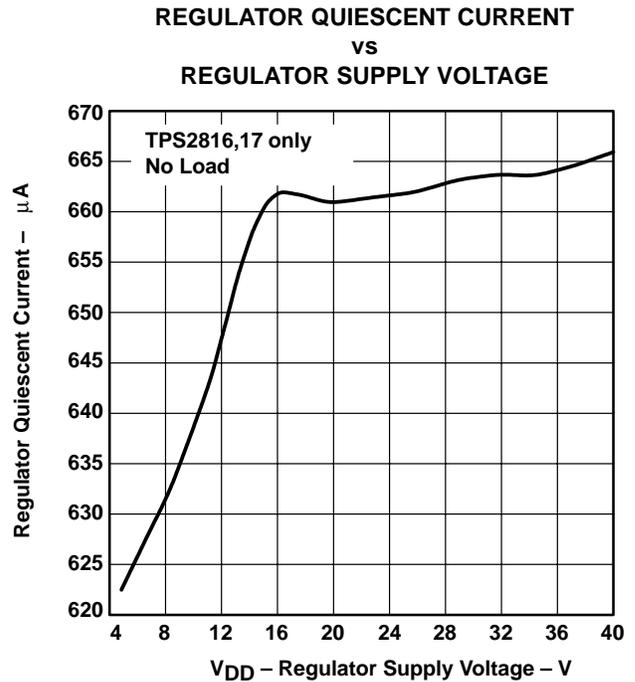


Figure 17

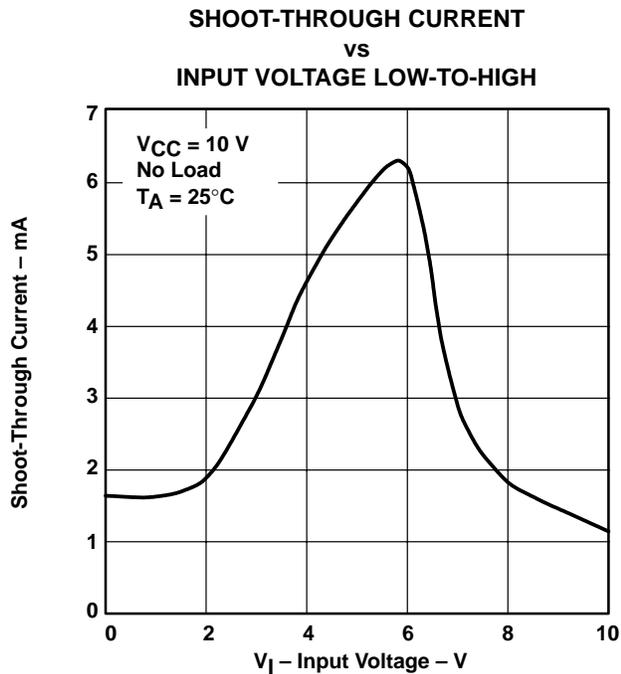


Figure 18

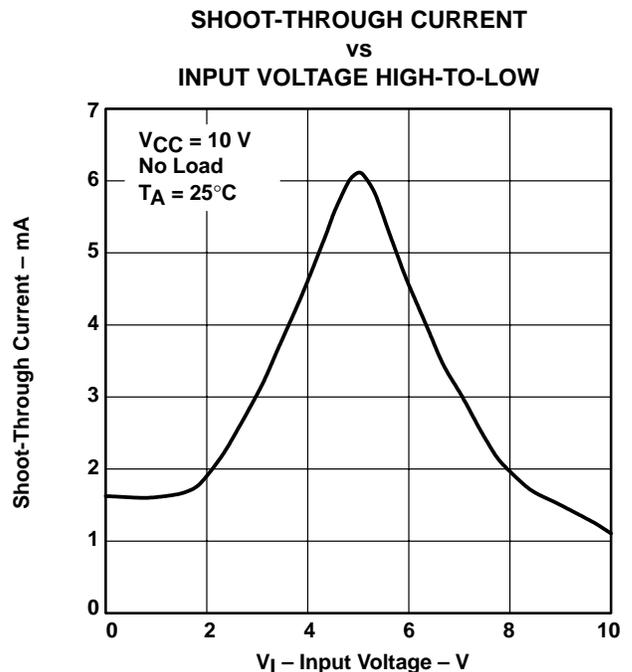


Figure 19

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

APPLICATION INFORMATION

MOSFETs are voltage-driven devices that require very little steady-state drive current. However, the large input capacitance (200 pF to 3000 pF or greater) of these devices requires large current surges to reduce the turn-on and turn-off times. The TPS2816 series of high-speed drivers can supply up to 2 A to a MOSFET, greatly reducing the switching times. The fast rise times and fall times and short propagation delays allow for operation in today's high-frequency switching converters.

In addition, MOSFETs have a limited gate-bias voltage range, usually less than 20 V. The TPS2816 series of drivers extends this operating range by incorporating an on-board series regulator with an input range up to 40 V. This regulator can be used to power the drivers, the PWM chip, and other circuitry, providing the power dissipation rating is not exceeded.

When using these devices, care should be exercised in the proper placement of the driver, the switching MOSFET, and the bypass capacitor. Because of the large input capacitance of the MOSFET, the driver should be placed close to the gate to eliminate the possibility of oscillations caused by trace inductance ringing with the gate capacitance of the MOSFET. When the driver output path is longer than approximately 2 inches, a resistor in the range of 10 Ω should be placed in series with the gate drive as close as possible to the MOSFET. A ceramic bypass capacitor is also recommended to provide a source for the high-speed current transients that the MOSFET requires. This capacitor should be placed between V_{CC} and GND of the driver (see Figures 20 and 21).

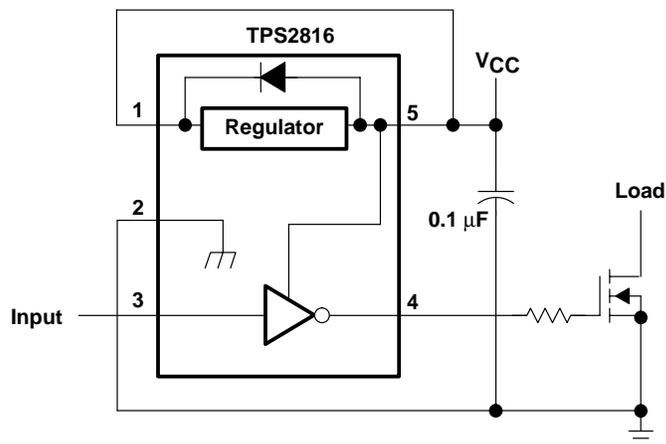


Figure 20. $V_{CC} < 14\text{ V}$

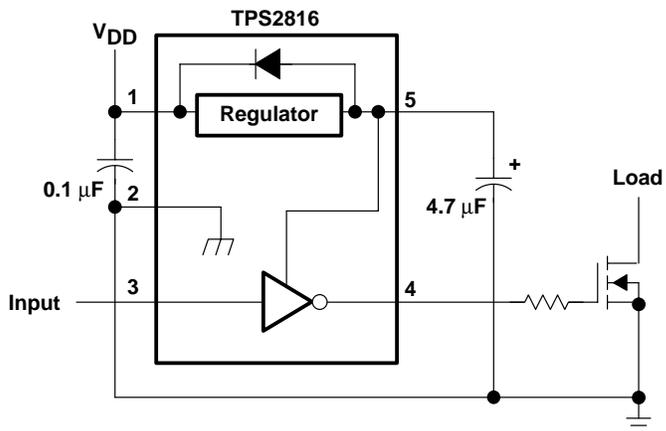


Figure 21. $V_{CC} > 14\text{ V}$

APPLICATION INFORMATION

The on-board series regulator supplies approximately 20 mA of current at 11.5 V, some of which can be used for external circuitry, providing the power dissipation rating for the driver is not exceeded. When using the on-board series regulator, an electrolytic output capacitor of 4.7 μF or larger is recommended. Although not required, a 0.1- μF ceramic capacitor on the input of the regulator can help suppress transient currents (see Figure 22). When not used, the regulator should be connected to V_{CC} . Grounding V_{DD} will result in destruction of the regulator.

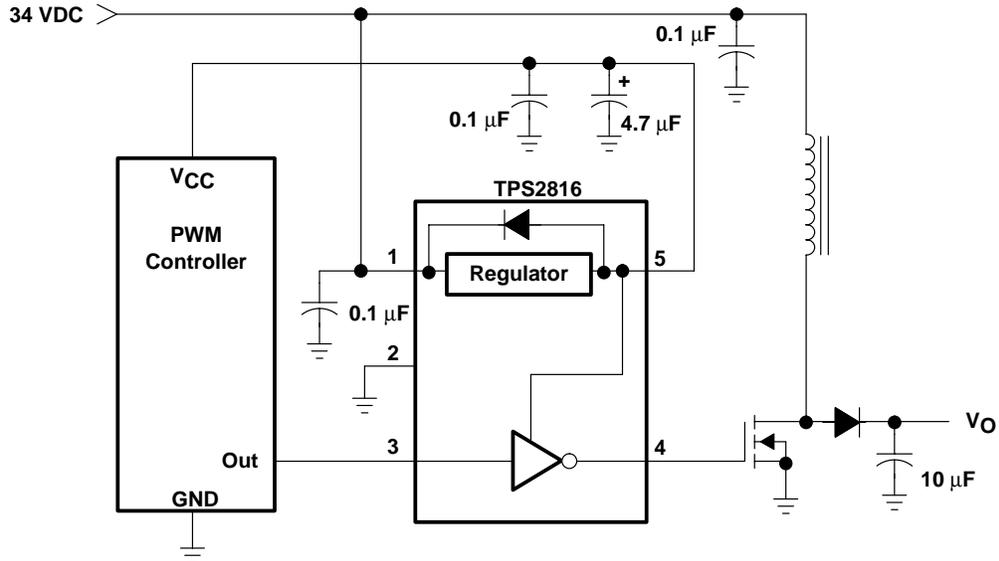


Figure 22. Boost Application

The TPS2816 and TPS2818 drivers include active pullup circuits on the inputs to eliminate the need for external pullup resistors when using controllers with open-collector outputs (such as the TL5001). The TPS2817 and TPS2819 drivers have standard CMOS inputs providing a total device operating current of less than 50 μA . All devices switch at standard CMOS logic levels of approximately $2/3 V_{CC}$ with positive-going input levels, and approximately $1/3 V_{CC}$ with negative-going input levels. Being CMOS drivers, these devices will draw relatively large amounts of current (Approximately 5 mA) when the inputs are in the range of one-half of the supply voltage. In normal operation, the driver input is in this range for a very short time. Care should be taken to avoid use of very low slew-rate inputs, used under normal operating conditions. Although not destructive to the device, slew rates slower than 0.1 V/ μs are not recommended.

The BiCMOS output stage provides high instantaneous drive current to rapidly toggle the power switch, and very low drop to each rail to ensure proper operation at voltage extremes.

Low-voltage circuits (less than 14 V) that require very low quiescent currents can use the TPS2828 and TPS2829 drivers. These drivers use typically 0.2 μA of quiescent current (with inputs high or low). They do not have the internal regulator or the active pullup circuit, but all other specifications are the same as for the rest of the family.

2.5-V/3.3-V, 3-A application

Figure 23 illustrates the use of the TPS2817 with a TL5001 PWM controller and a TPS1110 in a simple step-down converter application. The converter operates at 275 kHz and delivers either 2.5 V or 3.3 V (determined by the value of R_6) at 3 A (5 A peak) from a 5-V supply. The bill of materials is provided in Table 1.

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

APPLICATION INFORMATION

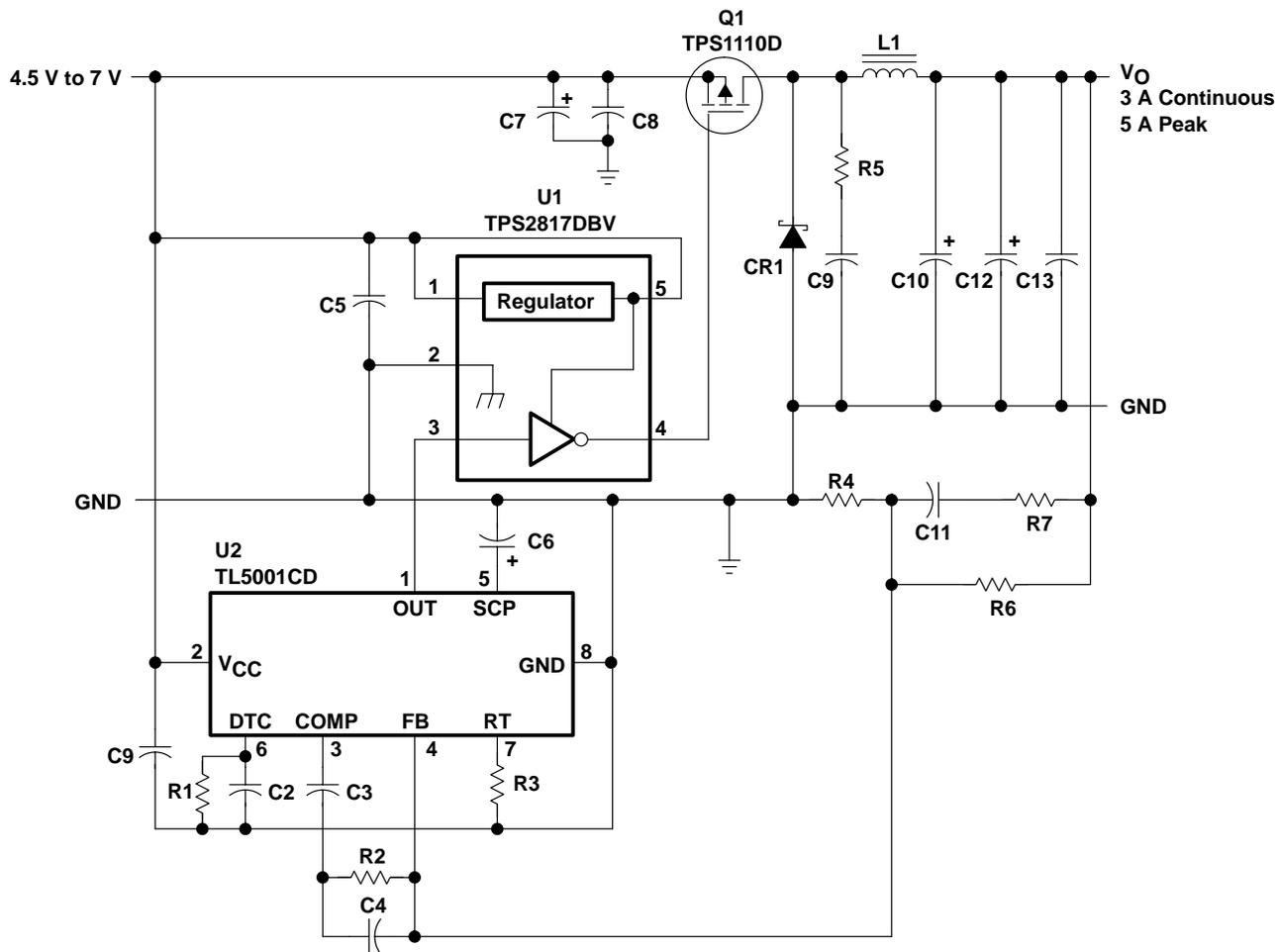


Figure 23. Step-Down Application

NOTE: If the parasitics of the external circuit cause the voltage to violate the Absolute Maximum Rating for the Output pins, Schottky diodes should be added from ground to output and from output to Vcc.

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

APPLICATION INFORMATION

Table 1. Bill of Materials

REF DES	PART NO.	DESCRIPTION	MFR
U1	TPS2817DBV	IC, MOSFET driver, single noninverting	TI
U2	TL5001CD	IC, PWM controller	TI
Q1	TPS1110D	MOSFET, p-channel, 6 A, 7 V, 75 m Ω	TI
C1, C2, C5, C8		Capacitor, ceramic, 0.1 μ F, 50 V, X7R, 1206	
C3		Capacitor, ceramic, 0.033 μ F, 50 V, X7R, 1206	
C4		Capacitor, ceramic, 2200 pF, 50 V, X7R, 0805	
C6	ECS-T1CY105R	Capacitor, tantalum, 1.0 μ F, 16 V, A case	Panasonic
C7	10SC47M	Capacitor, OS-Con, 47 μ F, 10 V	Sanyo
C9		Capacitor, ceramic, 1000 pF, 50 V, X7R, 0805	
C10, C12	10SA220M	Capacitor, OS-Con, 220 μ F, 10 V	Sanyo
C11		Capacitor, ceramic, 0.022 μ F, 50 V, X7R, 0805	
C13		Capacitor, ceramic, 47 μ F, 50 V, X7R	
CR1	50WQ03F	Diode, Schottky, D-pak, 5 A 30 V	IR
L1	SML3723	Inductor, 27 μ H, +/- 20%, 3 A	Nova Magnetics
R1		Resistor, CF, 47 k Ω , 1/10 W, 5%, 0805	
R2		Resistor, CF, 1.5 k Ω , 1/10 W, 5%, 0805	
R3		Resistor, MF, 30.1 k Ω , 1/10 W, 1%, 0805	
R4		Resistor, MF, 1.00 k Ω , 1/10 W, 1%, 0805	
R5		Resistor, CF, 47 Ω , 1/10 W, 5%, 0805	
R6 (3.3-V)		Resistor, MF, 2.32 k Ω , 1/10 W, 1%, 0805	
R6 (2.5-V)		Resistor, MF, 1.50 k Ω , 1/10 W, 1%, 0805	
R7		Resistor, CF, 100 Ω , 1/10 W, 5%, 0805	

As shown in Figures 24 and 25, the TPS2817 turns on the TPS1110 power switch in less than 20 ns and off in 25 ns.

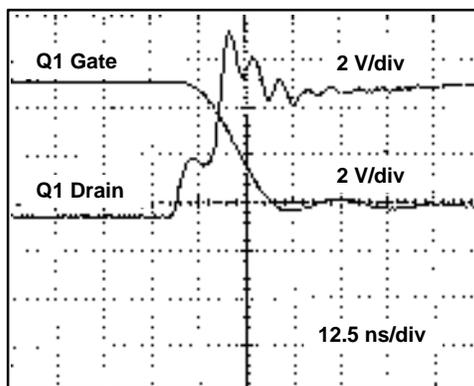


Figure 24. Q1 Turn-On Waveform

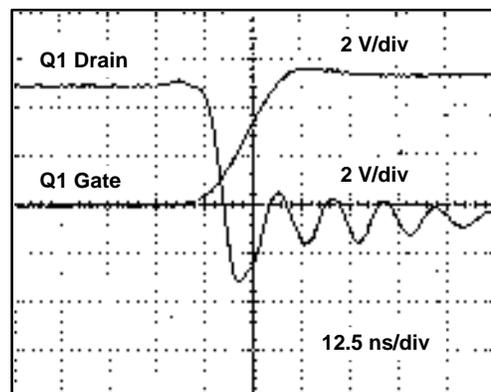


Figure 25. Q1 Turn-Off Waveform

TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829, SINGLE-CHANNEL HIGH-SPEED MOSFET DRIVER

SLVS160C – FEBRUARY 1997 – REVISED OCTOBER 2002

APPLICATION INFORMATION

The efficiency for various output currents, with a 5.25-V input, is shown in Figure 26. For a 3.3-V output, the efficiency is greater than 90% for loads up to 2 A – exceptional for a simple, inexpensive design.

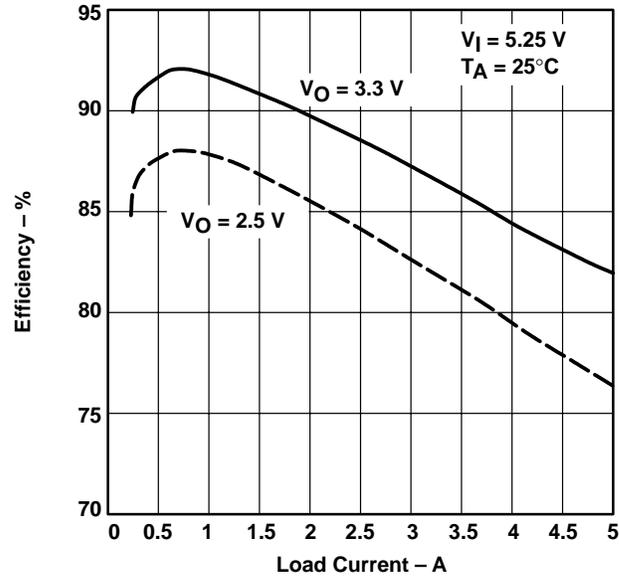


Figure 26. Converter Efficiency

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPS2816DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI			
TPS2816DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PAAI	Samples
TPS2816DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PAAI	Samples
TPS2816DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PAAI	Samples
TPS2816DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PAAI	Samples
TPS2817DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI			
TPS2817DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PABI	Samples
TPS2817DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PABI	Samples
TPS2817DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PABI	Samples
TPS2817DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PABI	Samples
TPS2818DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI			
TPS2818DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PACI	Samples
TPS2818DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PACI	Samples
TPS2819DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI			
TPS2819DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PADI	Samples
TPS2819DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PADI	Samples
TPS2819DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PADI	Samples
TPS2819DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PADI	Samples
TPS2828DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI			

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPS2828DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PAXI	Samples
TPS2828DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PAXI	Samples
TPS2828DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PAXI	Samples
TPS2828DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		PAXI	Samples
TPS2829DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI			
TPS2829DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAYI	Samples
TPS2829DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAYI	Samples
TPS2829DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAYI	Samples
TPS2829DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PAYI	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

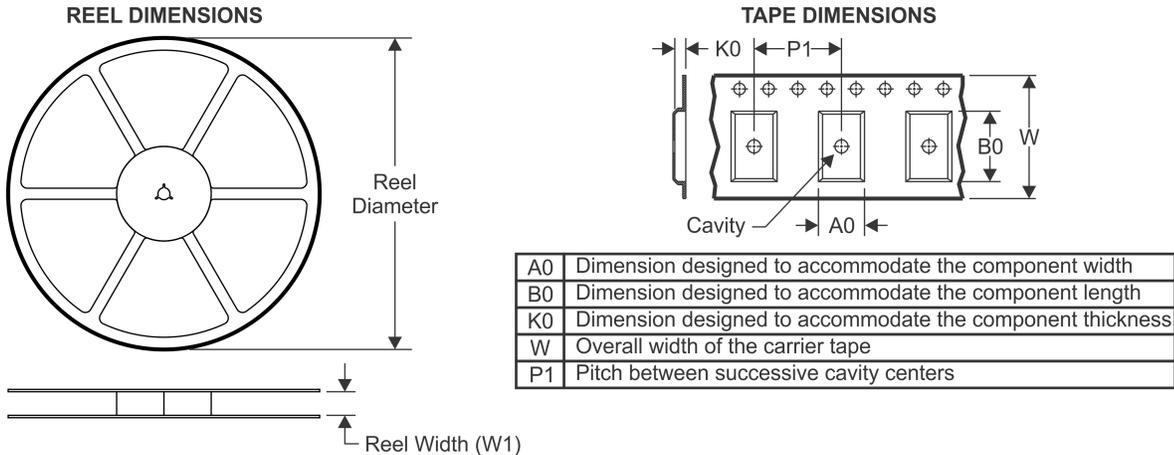
OTHER QUALIFIED VERSIONS OF TPS2816, TPS2817, TPS2818, TPS2819, TPS2828, TPS2829 :

- Automotive: [TPS2819-Q1](#), [TPS2829-Q1](#)
- Enhanced Product: [TPS2816-EP](#), [TPS2817-EP](#), [TPS2818-EP](#), [TPS2819-EP](#), [TPS2828-EP](#)

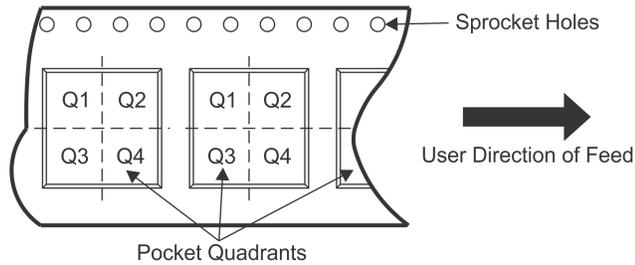
NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

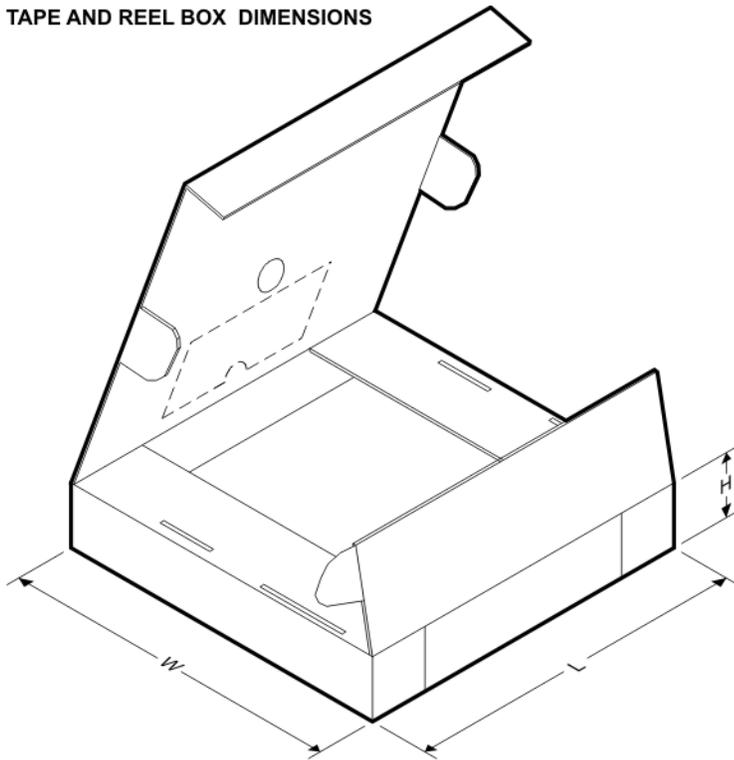


QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS2816DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS2816DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS2817DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS2817DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS2818DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS2819DBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS2819DBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TPS2828DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS2828DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS2829DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS2829DBVT	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS2816DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS2816DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS2817DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS2817DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS2818DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS2819DBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TPS2819DBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TPS2828DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS2828DBVR	SOT-23	DBV	5	3000	203.0	203.0	35.0
TPS2828DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
TPS2829DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
TPS2829DBVT	SOT-23	DBV	5	250	180.0	180.0	18.0

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com

AMEYA360

Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype [ameyasales1](#) [ameyasales2](#)

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com